

HMC584LP5 / 584LP5E

v03.1210



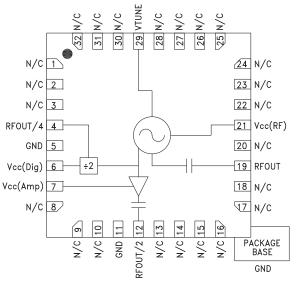
MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-4, 12.5 - 13.9 GHz

Typical Applications

Low noise MMIC VCO w/Half Frequency, Divide-by-4 Outputs for:

- Point to Point/Multipoint Radio
- Test Equipment & Industrial Controls
- SATCOM
- Military End-Use

Functional Diagram



Features

Dual Output: Fo = 12.5 - 13.9 GHzFo/2 = 6.25 - 6.95 GHz

Pout: +10 dBm

Phase Noise: -110 dBc/Hz @100 kHz Typ.

No External Resonator Needed

32 Lead 5x5mm SMT Package: 25mm²

General Description

The HMC584LP5 & HMC584LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC584LP5 & HMC584LP5E integrate resonators, negative resistance devices, varactor diodes and feature half frequency and divide-by-4 outputs. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +10 dBm typical from a +5V supply voltage. The prescaler and RF/2 functions can be disabled to conserve current if not required. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc (Dig), Vcc (Amp), Vcc (RF) = +5V

Parameter		Min.	Тур.	Max.	Units
Frequency Range	Fo Fo/2		12.5 - 13.9 6.25 - 6.95		GHz GHz
Power Output	RFOUT/2 RFOUT/4	+7 +8 -9		+14 +14 -3	dBm dBm dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RFOUT			-110		dBc/Hz
Tune Voltage	Vtune	2		12	V
Supply Current	Icc(Dig) + Icc(Amp) + Icc(RF)	290	330	380	mA
Tune Port Leakage Current (Vtune= 12V)				10	μA
Output Return Loss			2		dB
Harmonics/Subharmonics	1/2 3/2 2nd 3rd		28 34 29 40		dBc dBc dBc dBc
Pulling (into a 2.0:1 VSWR)			3		MHz pp
Pushing @ Vtune= 5V			20		MHz/V
Frequency Drift Rate			1.5		MHz/°C

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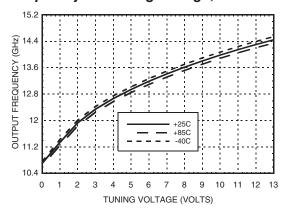


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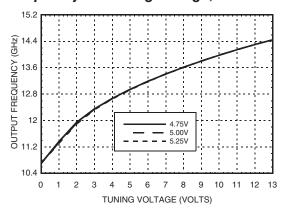


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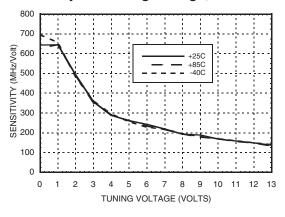
Frequency vs. Tuning Voltage, Vcc = +5V



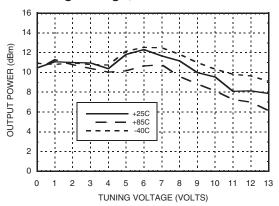
Frequency vs. Tuning Voltage, T= 25°C



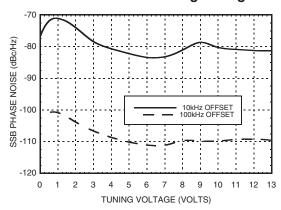
Sensitivity vs. Tuning Voltage, Vcc = +5V



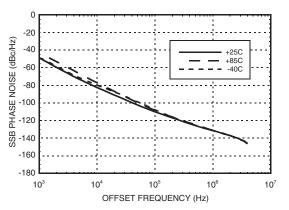
Output Power vs. Tuning Voltage, Vcc = +5V



SSB Phase Noise vs. Tuning Voltage



SSB Phase Noise @ Vtune = +5V

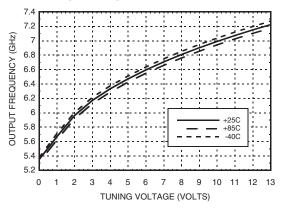






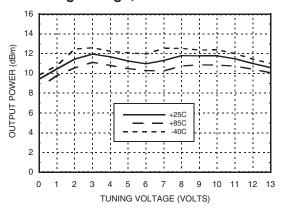
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RFOUT/2 Frequency vs. Tuning Voltage, Vcc = +5V

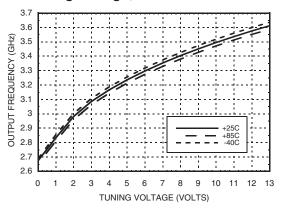


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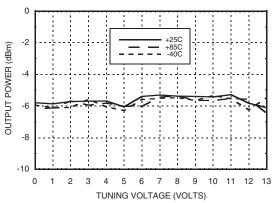
RFOUT/2 Output Power vs. Tuning Voltage, Vcc = +5V



Divide-by-4 Frequency vs. Tuning Voltage, Vcc = +5V



Divide-by-4 Output Power vs. Tuning Voltage, Vcc = +5V



Absolute Maximum Ratings

Vcc(Dig), Vcc(Amp), Vcc(RF)	+5.5 Vdc
Vtune	0 to +15V
Junction Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 43.5 mW/C above 85 °C	2.17 W
Thermal Resistance (junction to ground paddle)	23 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	300
5.00	330
5.25	360

Note: VCO will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

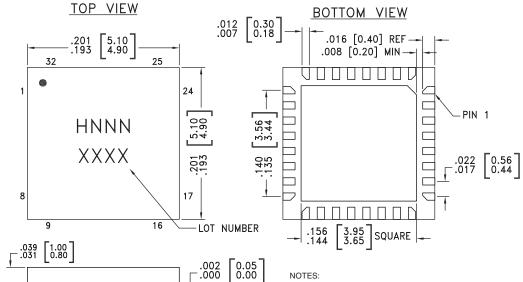


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Outline Drawing



SEATING

-C-

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

☐ .003[0.08] C

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC584LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 [1]	H584 XXXX
HMC584LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 [2]	H584 XXXX

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 3, 8 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/ DC ground. Performance will not be affected.	
4	RFOUT/4	Divide-by-4 output. DC block required.	5V ORFOUT/4
6	Vcc (Dig)	Supply voltage for prescaler. If prescaler is not required, this pin may be left open to conserve approximately 65 mA of current.	Vcc(Dig)





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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
7	Vcc (Amp)	Supply voltage, for RFOUT/2 output. If RFOUT/2 is not required, this pin may be left open to conserve approximately 30 mA of current.	Vcc(Amp) 14pF
12	RFOUT/2	Half frequency output (AC coupled).	PFOUT/2
19	RF OUT	RF output (AC coupled).	RFOUT
21	Vcc (RF)	Supply Voltage, +5V	Vec(RF) 14pF
29	VTUNE	Control voltage and modulation input. Modulation bandwidth dependent on drive source impedance. See "Determining the FM Bandwidth of a Wideband Varactor Tuned VCO" application note.	3nH VTUNE 0
5, 11, Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	- GND

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Typical Application Circuit

